



Materiale nanostructurate: aplicatii practice in nanomedicina si bio-senzoristica

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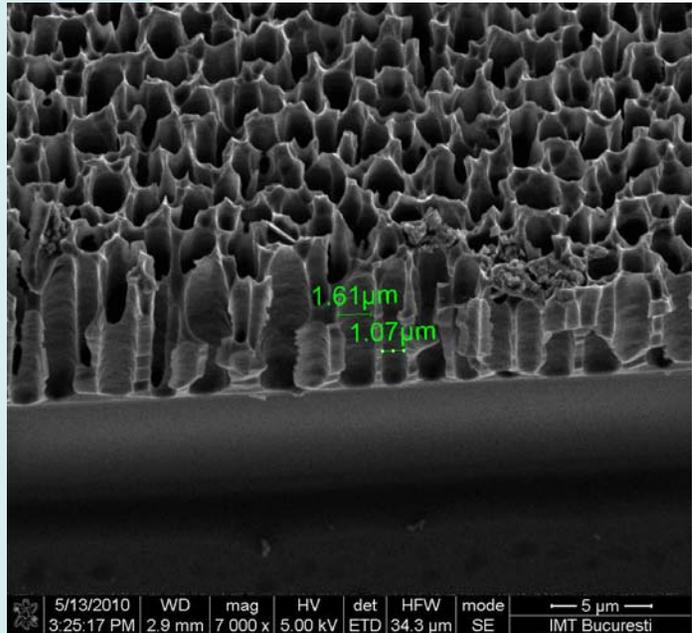
- Si – porous Si
- Au – Au (111)
- Graphene – metallic nanoparticles decorated
- Applications



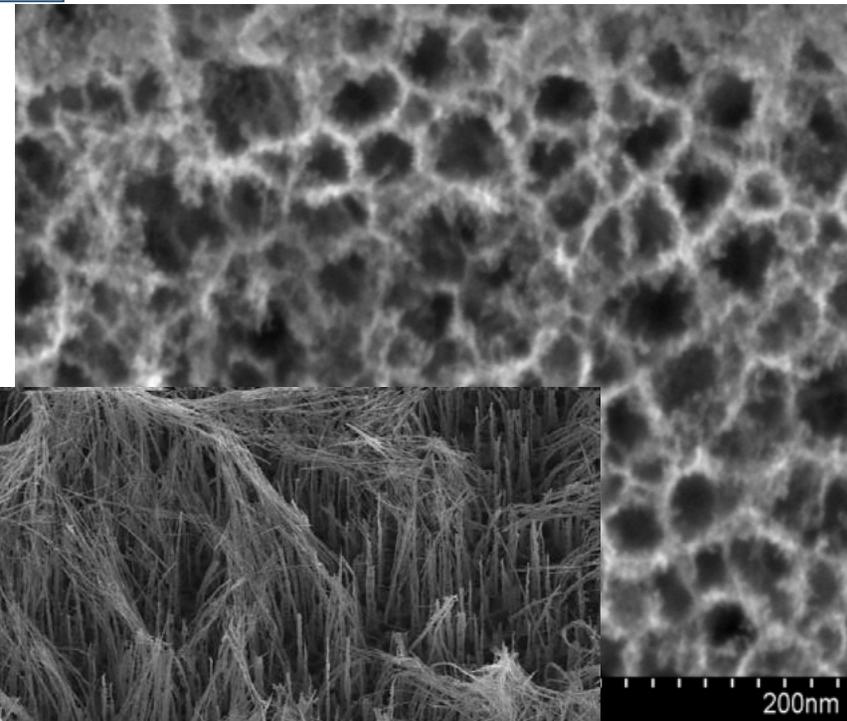
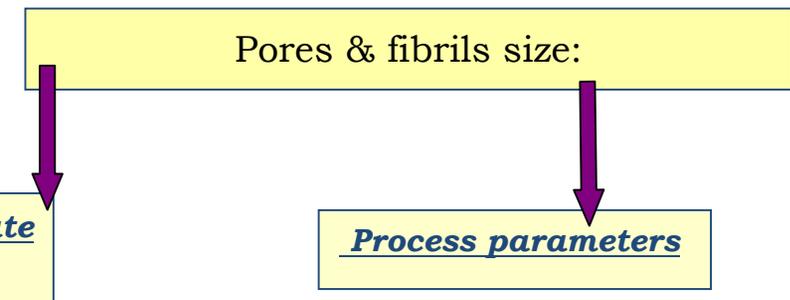
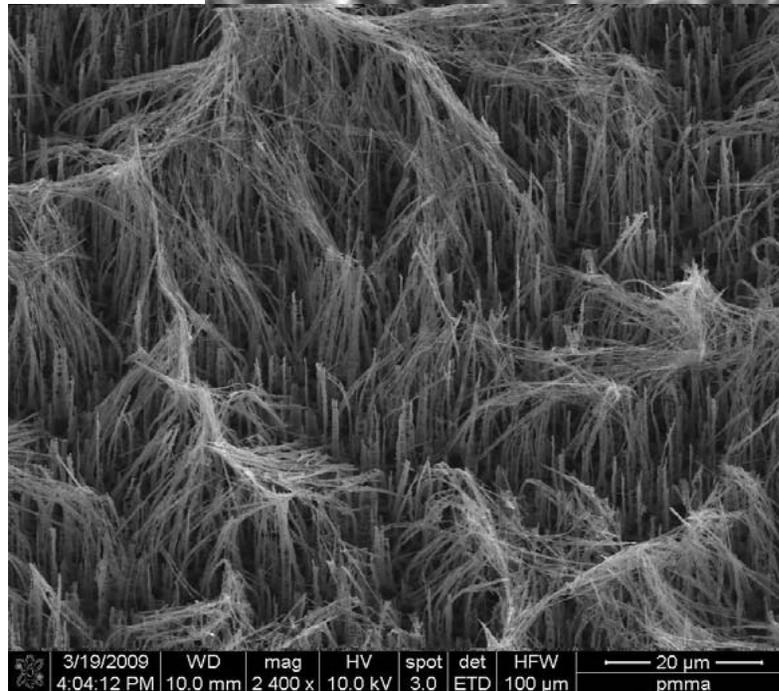
Si

SEM - PS morphology

macro-PS (1- 2 μm)

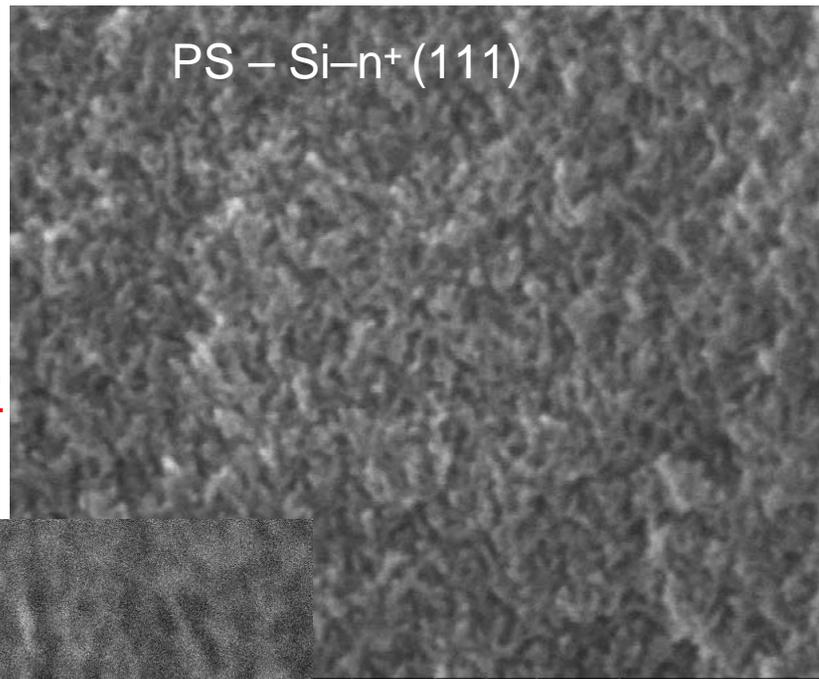
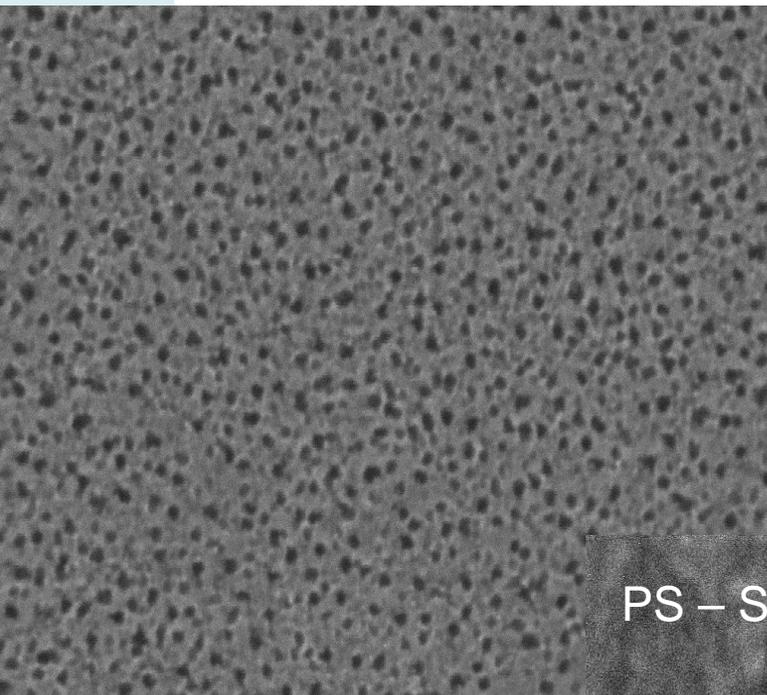


meso-PS
(50 - 100 nm)

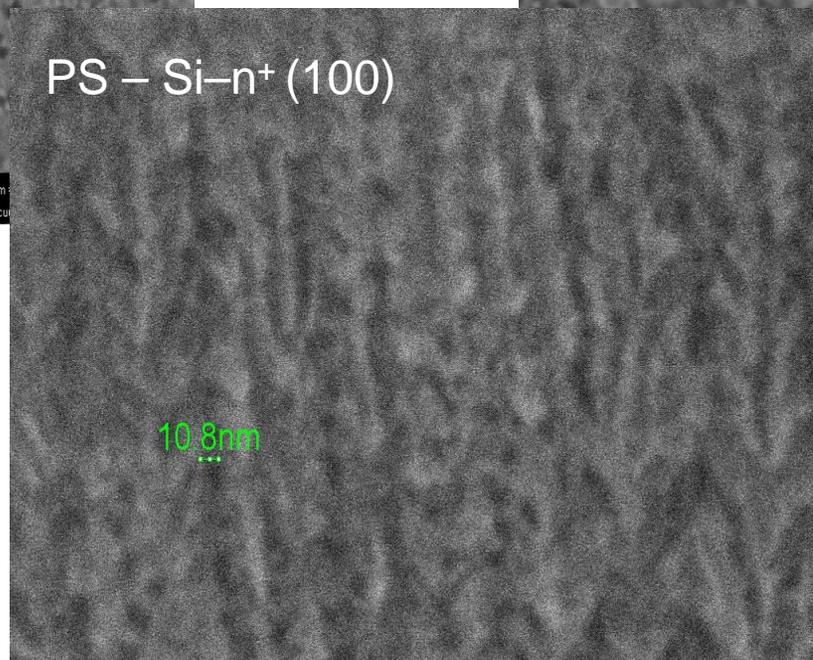




SEM - PS morphology



nano-PS
(< 15 nm)



SUPRA 35-29-87 Mag = 143.66 KX EHT = 10.00 kV Signal A = InLens Gun Vacuum Ext. Scan Control = Off 20 nm WD = 6.8 mm Aperture Size = 30.00 µm System Vacuum

g HV spot det HFW — 100 nm —
00 x 10.3 kV 3.0 TLD 480 nm

Si

3/19/2009 WD mag HV spot det HFW — 100 nm —
3:13:47 PM 5.6 mm 500 000 x 10.0 kV 3.0 TLD 480 nm si po



Si substrate

- type and level of doping;
- crystallographic orientation

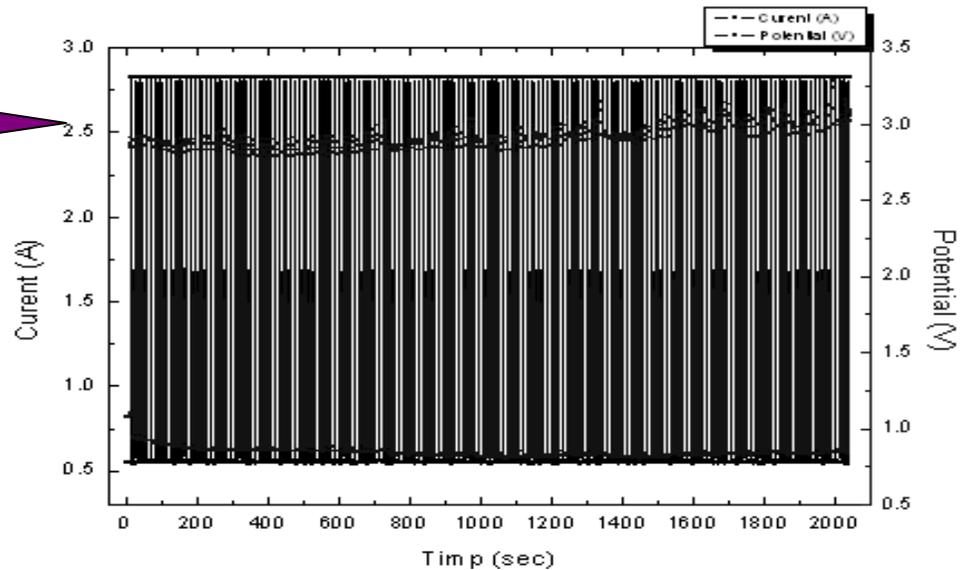
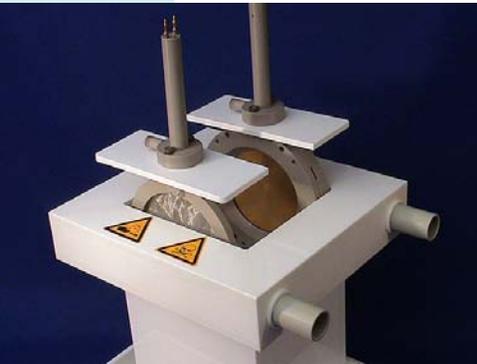
Pores & fibrils size depends on:

Process parameters

- electrolyte type / HF concentration;
- current density;
- illumination conditions.

Porous silicon – PS - is obtained by electrochemical dissolution of silicon in HF

PS layers, have been obtained using the A.M.M.T etching system for 4" Si wafers with programmable power supply and dedicated software for time-based current profiles.

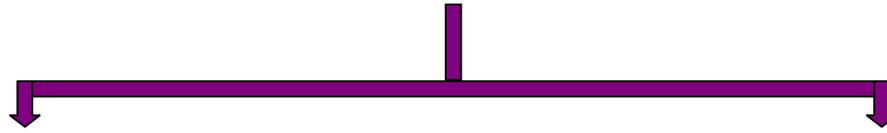


Current-potential-time diagram for 150 cycles (0.554 A, 10 sec, 2.825 A, 4 sec).

Si



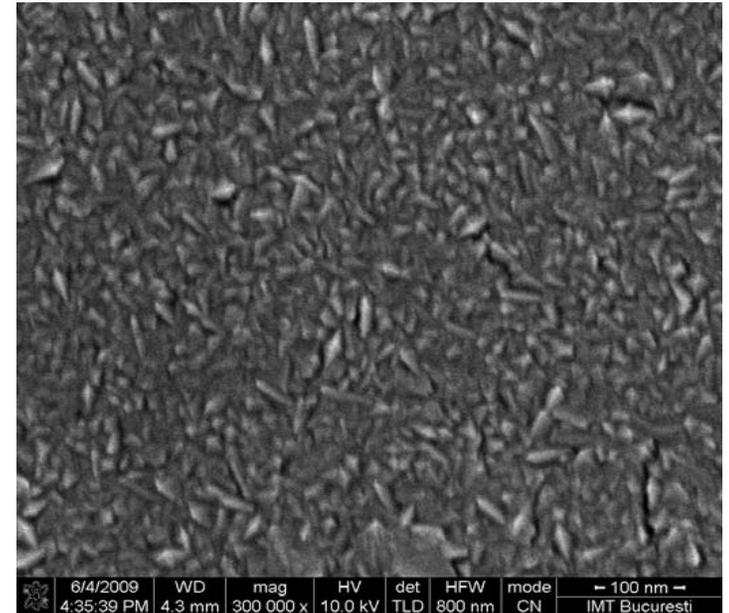
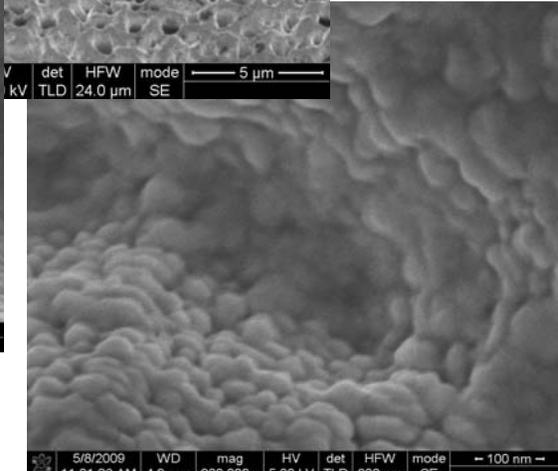
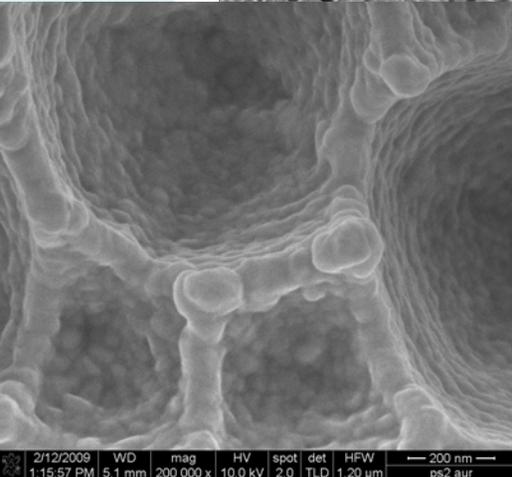
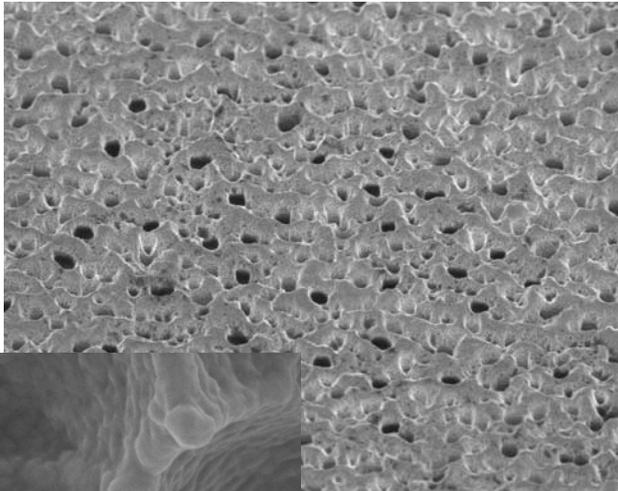
Nano-structured metallic thin films (NP-PVD) on PS substrate



Au thin films - 100 nm – cathodic sputtering system

Pt thin films - 100 nm
e-beam deposition system

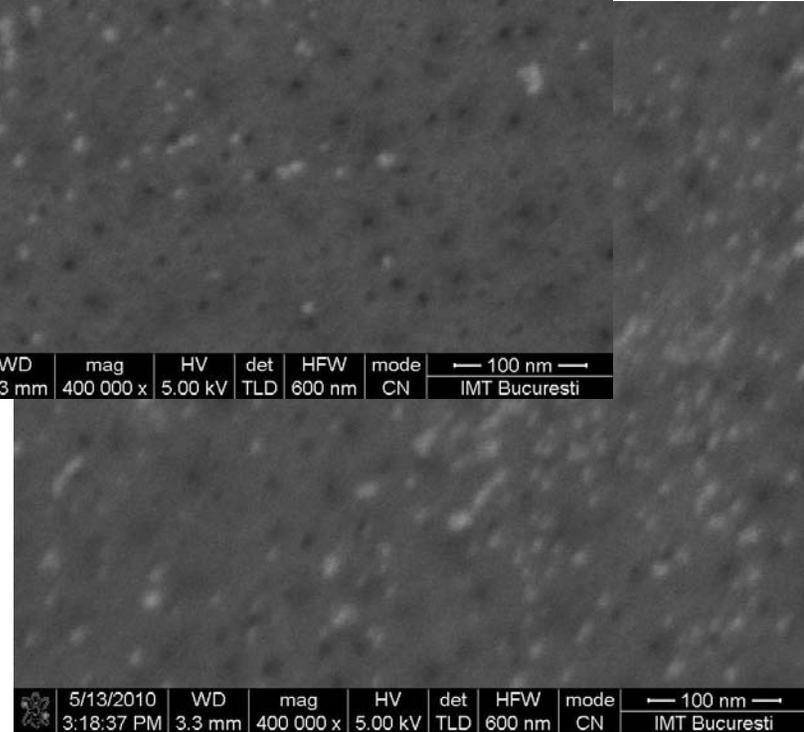
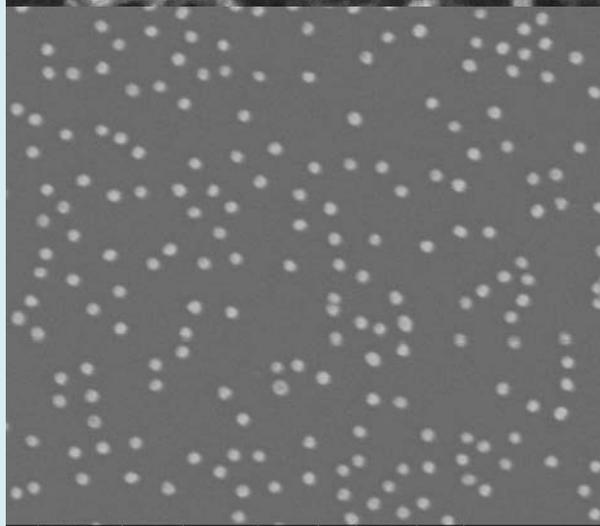
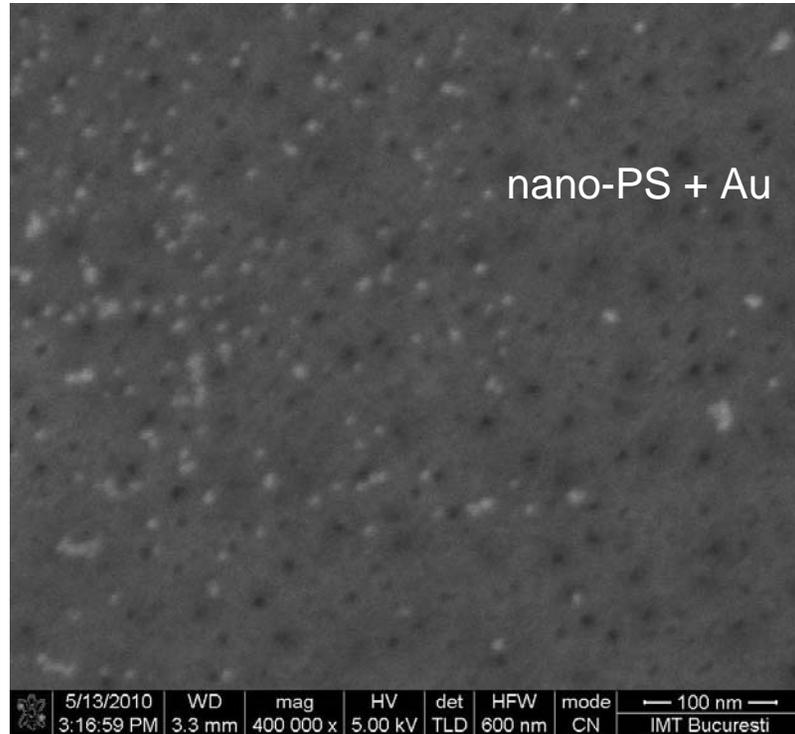
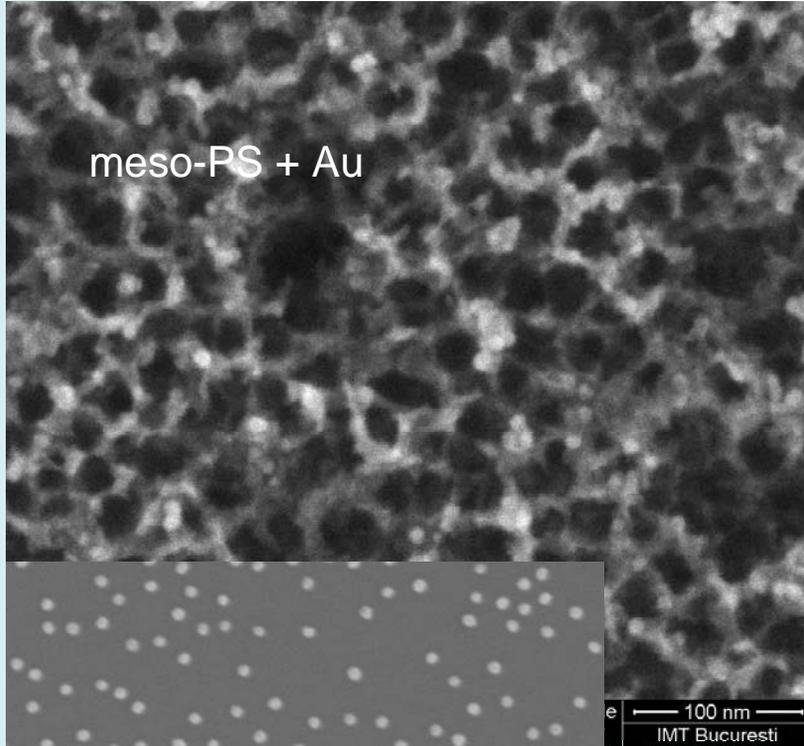
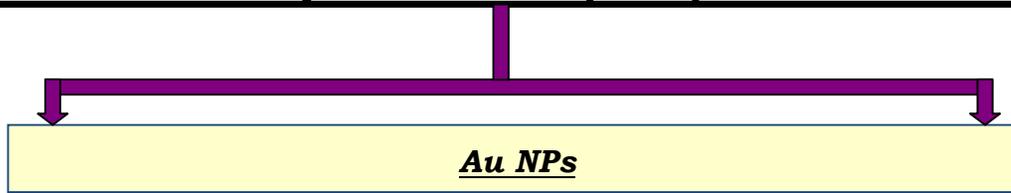
Si



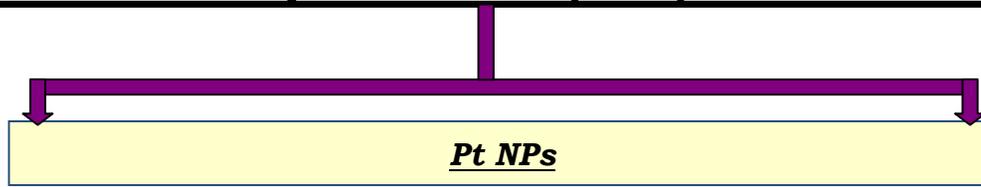


Si

Metallic nanoparticles (NP) on PS substrate

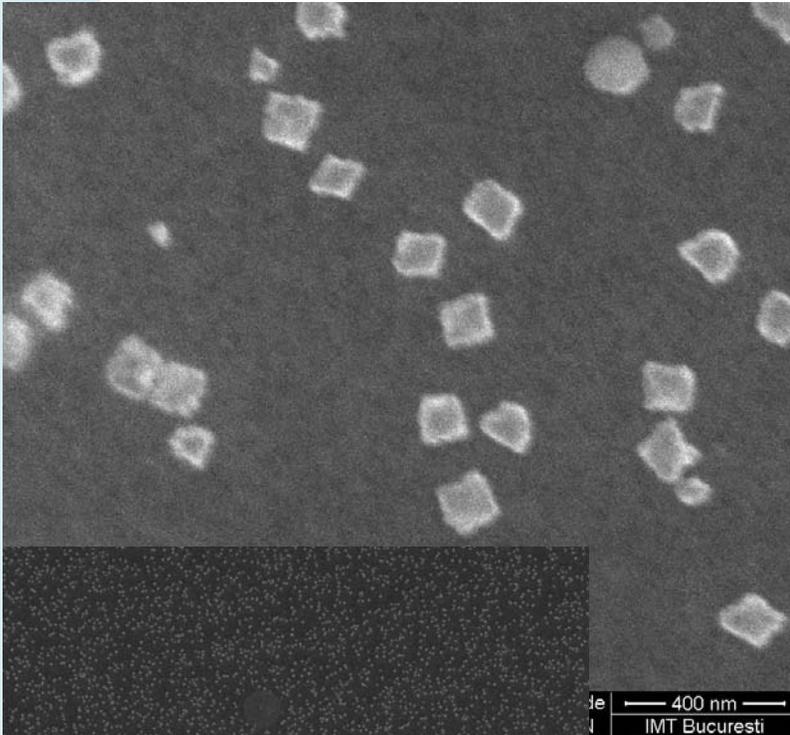


Metallic nanoparticles (NP) on PS substrate

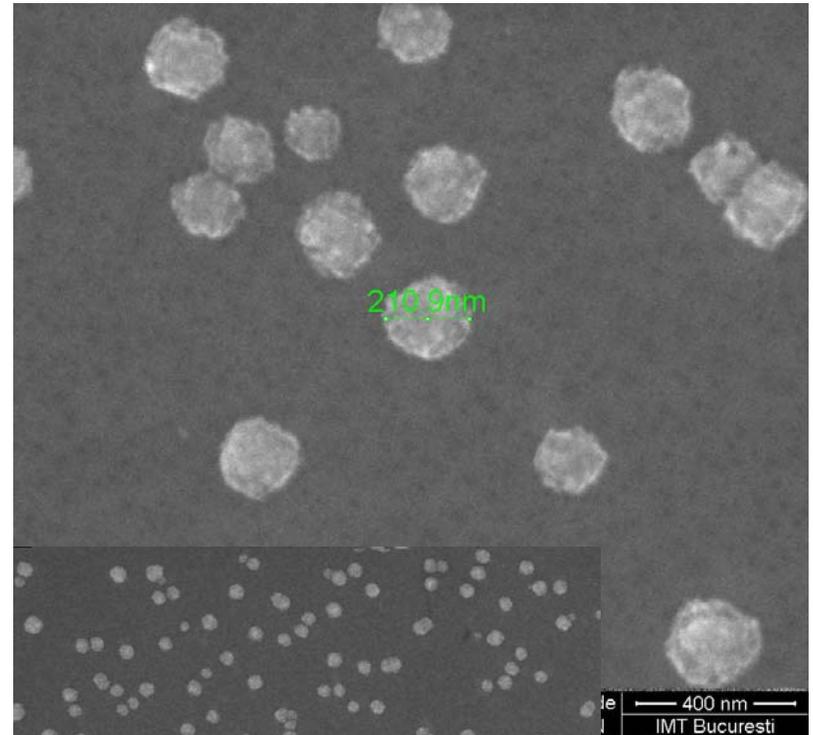


nano-PS + Pt

Si



5/11/2010 2:10:59 PM WD 3.6 mm mag 8 000 x HV 7.00 kV det ETD HFW 30.0 μ m mode SE μ m 5 IMT Bucuresti



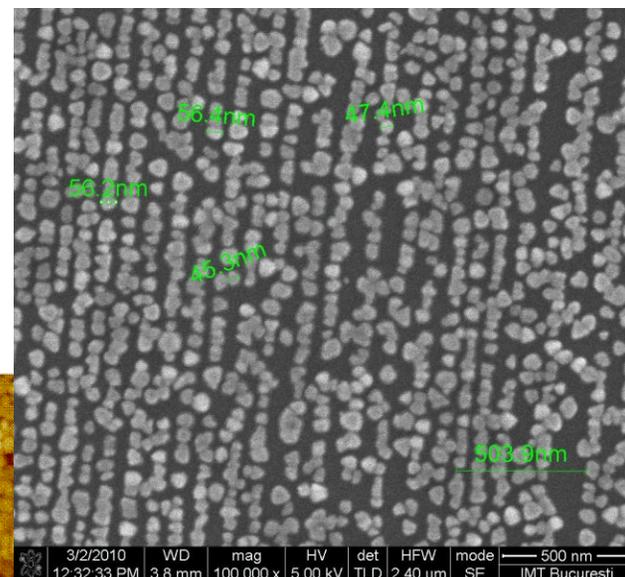
5/13/2010 3:10:29 PM WD 3.2 mm mag 30 000 x HV 5.00 kV det TLD HFW 8.00 μ m mode CN μ m 1 IMT Bucuresti

Electrochemically deposited Au (NP) on Si substrate

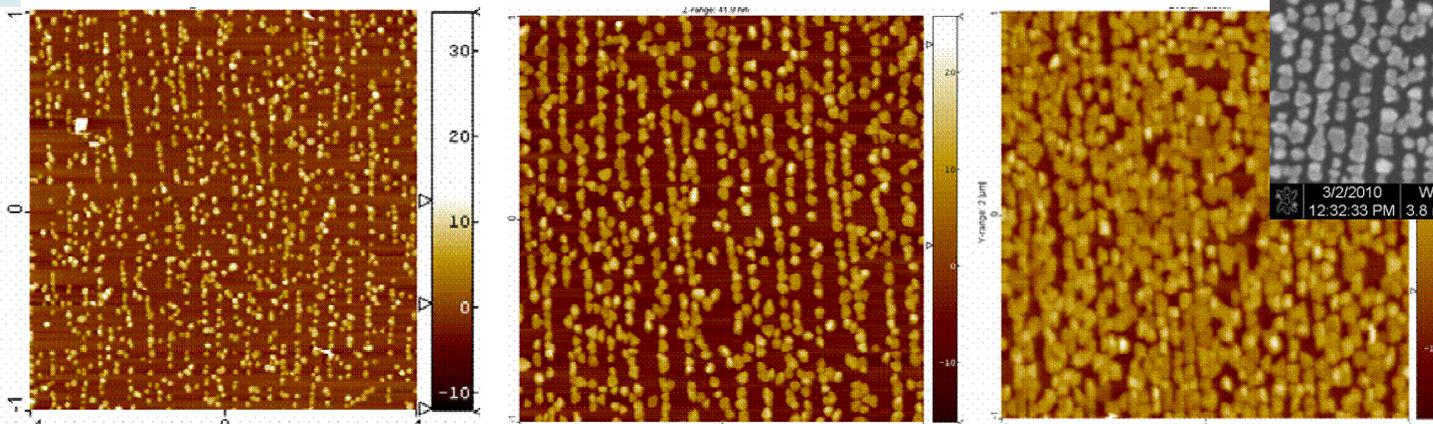
Si



Substrate preparation: $\text{H}_2\text{SO}_4:\text{H}_2\text{O}_2 = 1:3$ v/v;
Si(111)-H; $(\text{NH}_4\text{F } 40\%)$; $(\text{NH}_4)_2\text{SO}_3$; 15 min.
Electrochemical deposition of gold nanoislands
(0.1mM $\text{KAu}(\text{CN})_2$, 0.2mM NaCN, 2M NaOH,
pH=14).



AFM images of gold-nano-islands on n-type silicon (111) substrates



**(a) 4s -2V and
10s -1,5V**

I=10 nm
D= 50 nm

**(b) 4s -2V and
30s -1,5V**

I=50 nm
D= 70 nm

**(c) 4s -2V and
100s -1,5V**

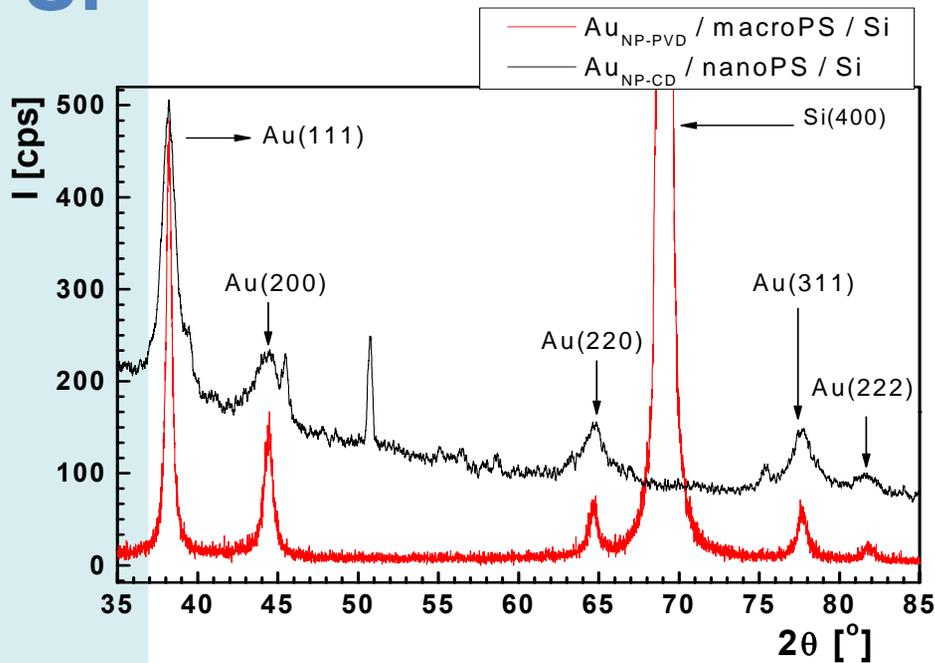
I=80 nm
D= 100 nm

Au nano-islands are prepared by electrochemical deposition on silicon.

X-ray diffraction

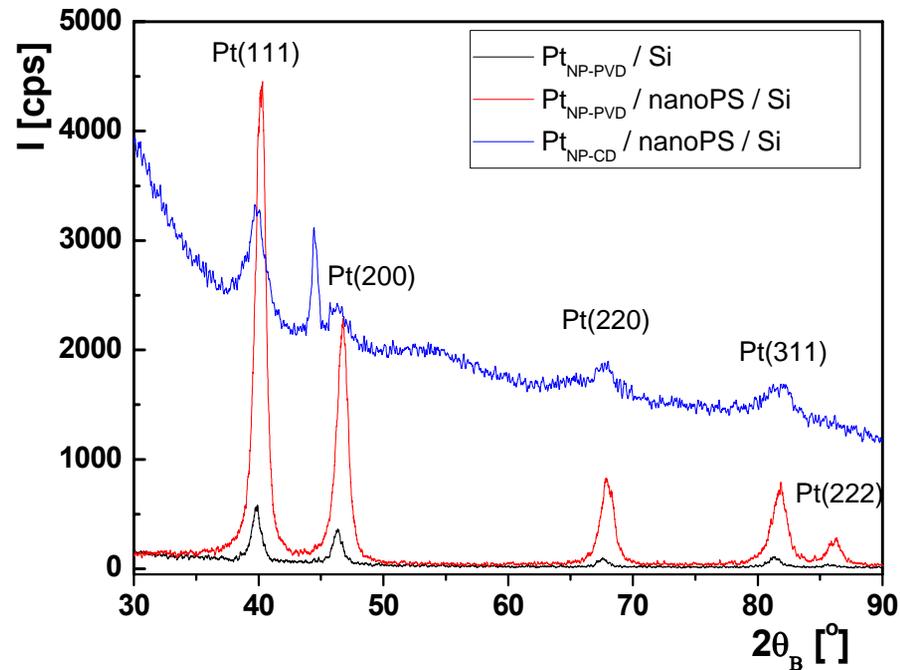
The microstructural characterisation of AuNP-PVD on macroPS and AuNP-CD on nanoPS.

Si



-XRD reveals the high intensity ratios between (111) diffraction pattern and the peaks assigned to (200), (220), (311), (222), and (400) reflections of fcc structure of gold, indicating that the faces of these nanoparticles were primarily composed of (111) planes.

GIXRD X-ray diffraction spectra ($\omega = 0.35^\circ$) of samples as function of both deposition method and substrate nature



- Pt_{NP-PVD} / Si : no preferential texture;
- Pt_{NP-PVD/CD} / PS / Si : indicates a better defined degree of crystallization with no preferential orientation.



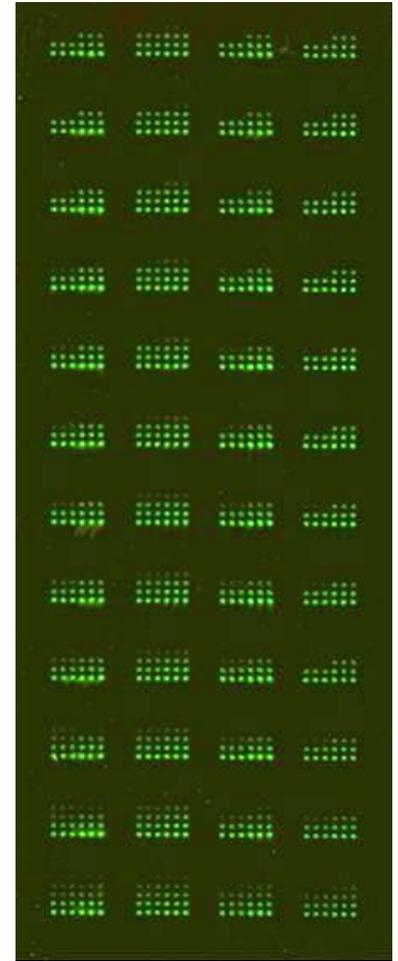
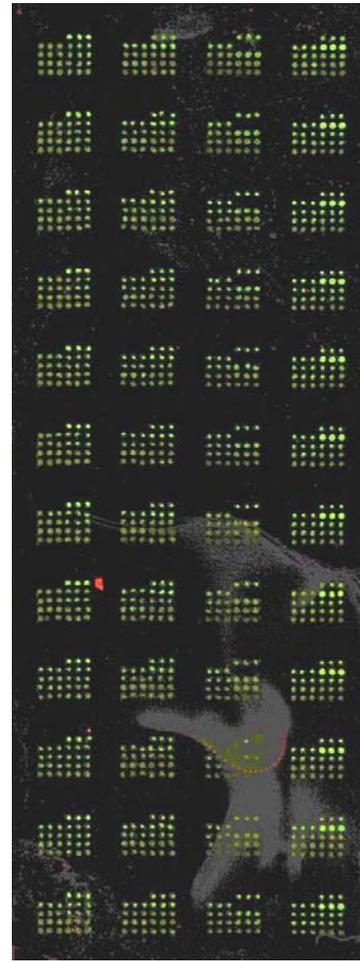
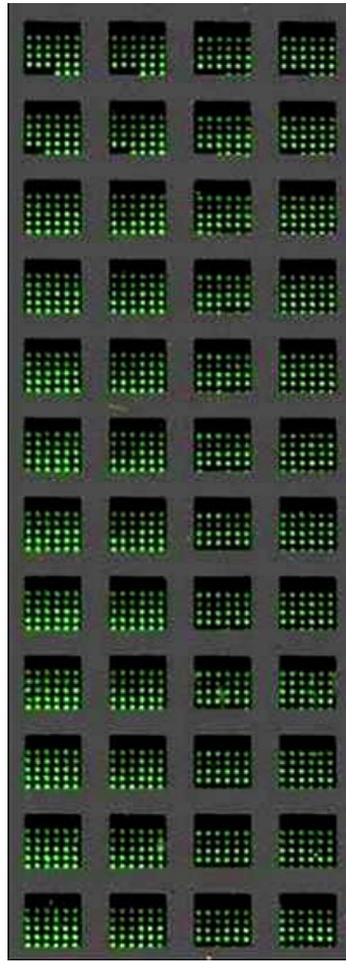
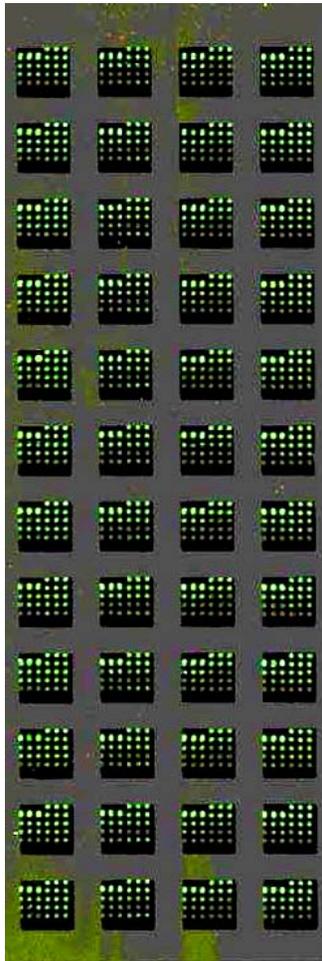
Practical applications

Microarray technology

Si

ALD -slides

p-L-lysine slides



GLASS

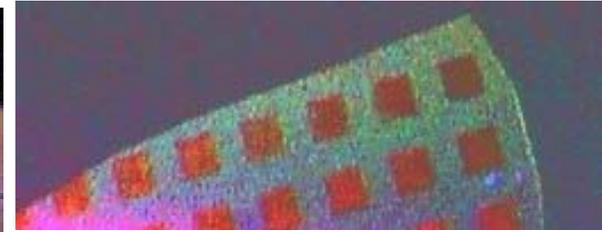
PS

PS

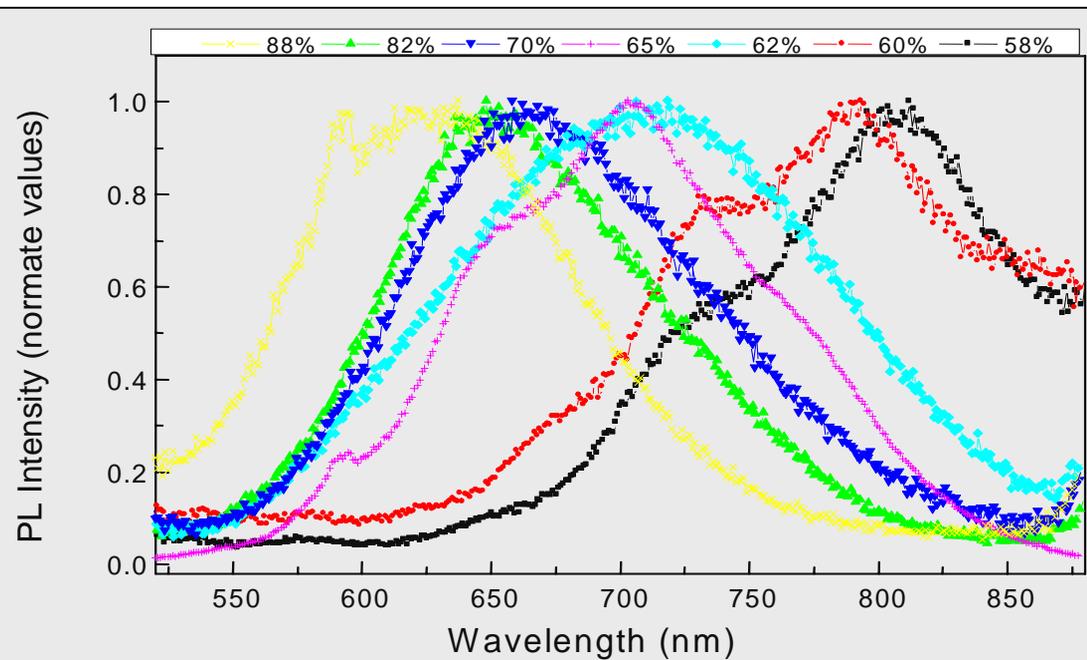
GLASS

Photoluminescence

The orange - red photoluminescence of nanoPS is clearly visible when the wafer illuminated by UV light.



No.	Concentration HF (%)	Current density (mA/cm ²)	Time (min)	Porosity (%)
1	25	15	6	58
2	25	20	6	60
3	25	25	6	62
4	18	15	6	65
5	18	20	6	70
6	15	15	6	80
7	15	25	6	88



Photoluminescence spectra of PS / Si-p samples with different porosities (58% - 88%)

Si

- the PL peaks for high porosity PS samples are centred around 650-720 nm, in visible range due to quantum confinement and surface states effects;
- a shift of the PL peak position towards high photon energies with the increase of the PS porosity is observed;

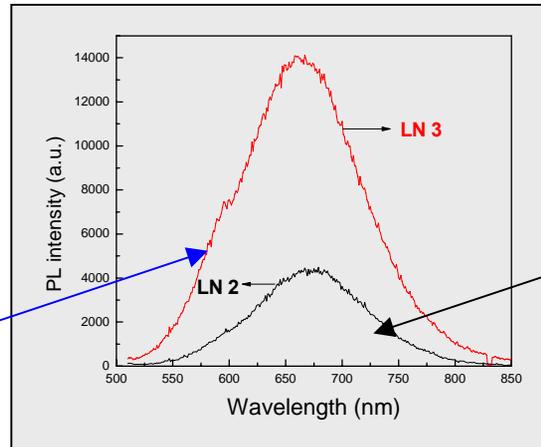
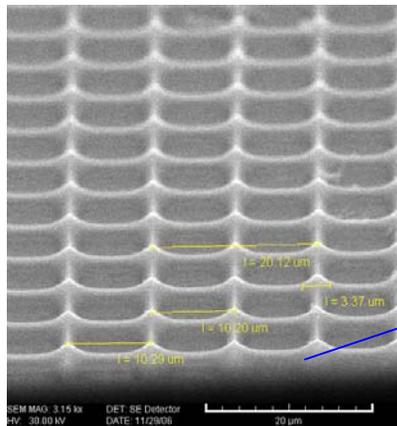
The PL emission from PS is observable at wavelengths ranging from the UV to the IR, the normalized spectra recorded for different experimental samples demonstrate the dependence on porosity.

Si microstructuration and porosification

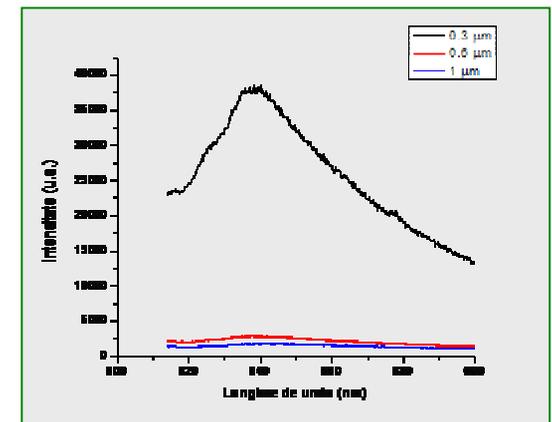
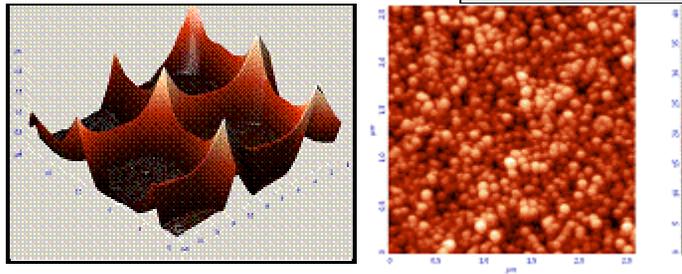
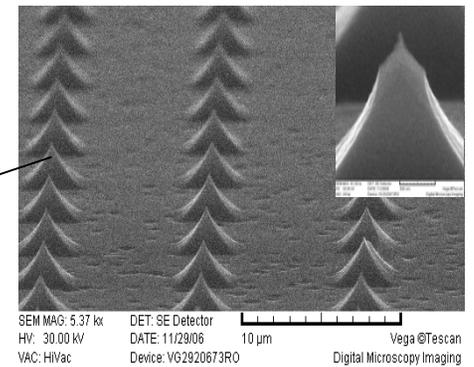
Si

Silicon substrate was micropatterned prior porosification process as:
an **array of pyramids** (right) or as **semi-circular cavities** (left);

LN3 interconnected lines

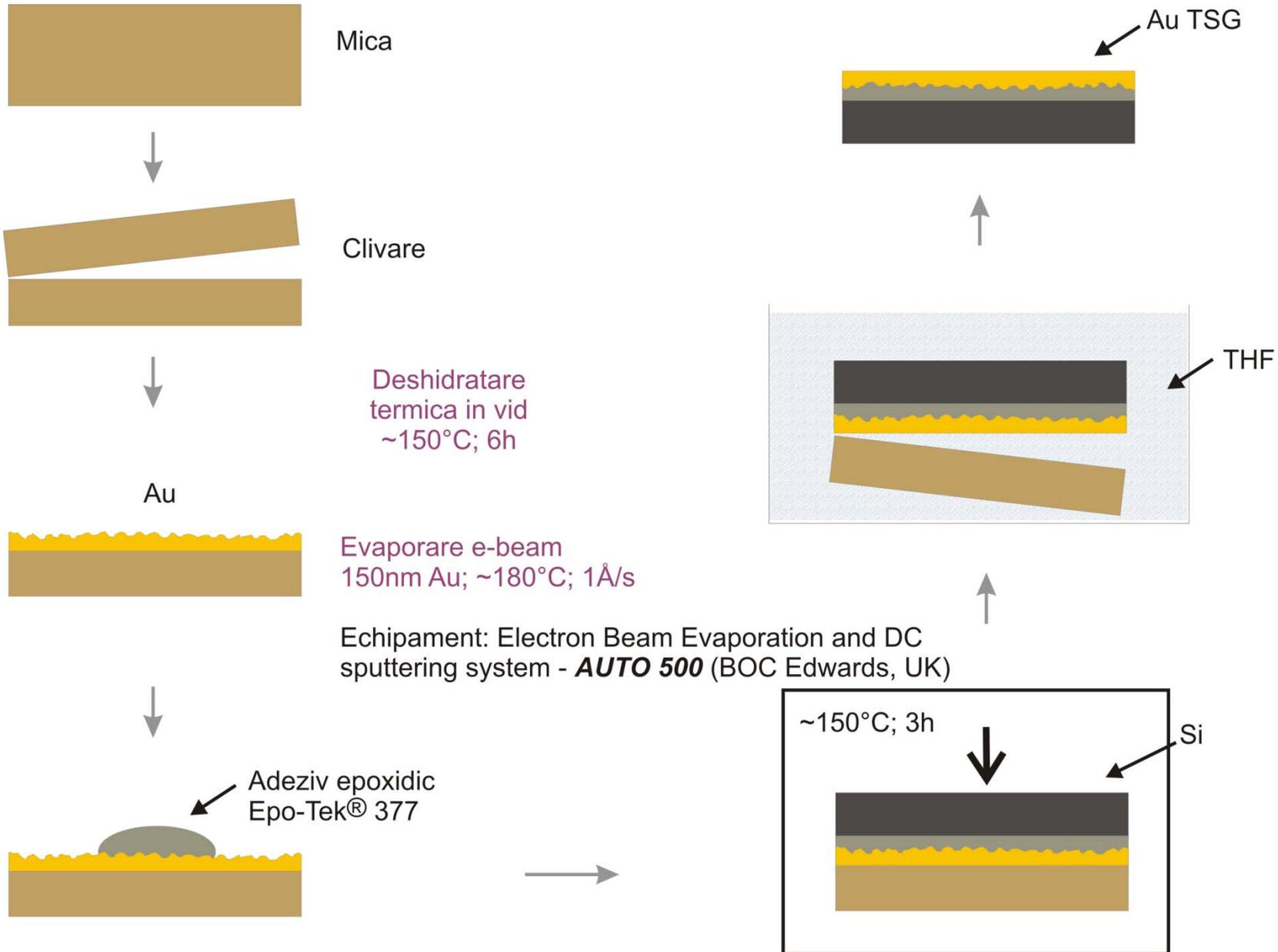


LN2 pyramidal structures



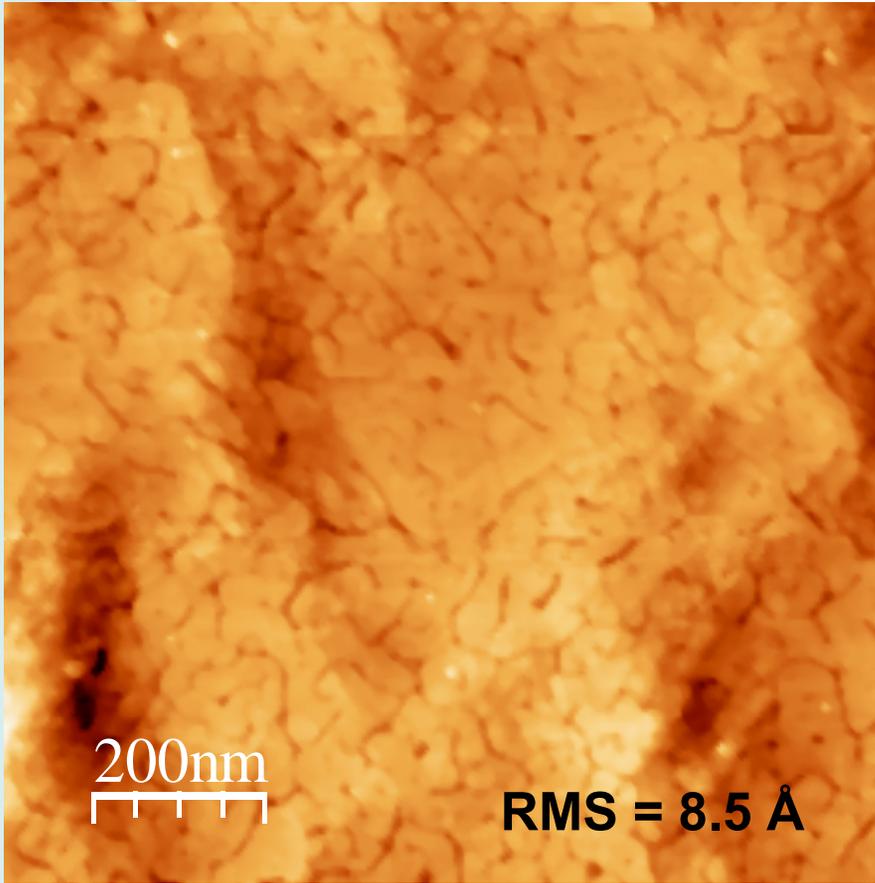
- **similar recording conditions were** (488 nm frequency of excitation and 87 mW nominal power)
- **the intensity of PL emission is three times larger in the case of semicircular microcavities** leading to an important improvement of detection.

TSG - "template stripped gold"

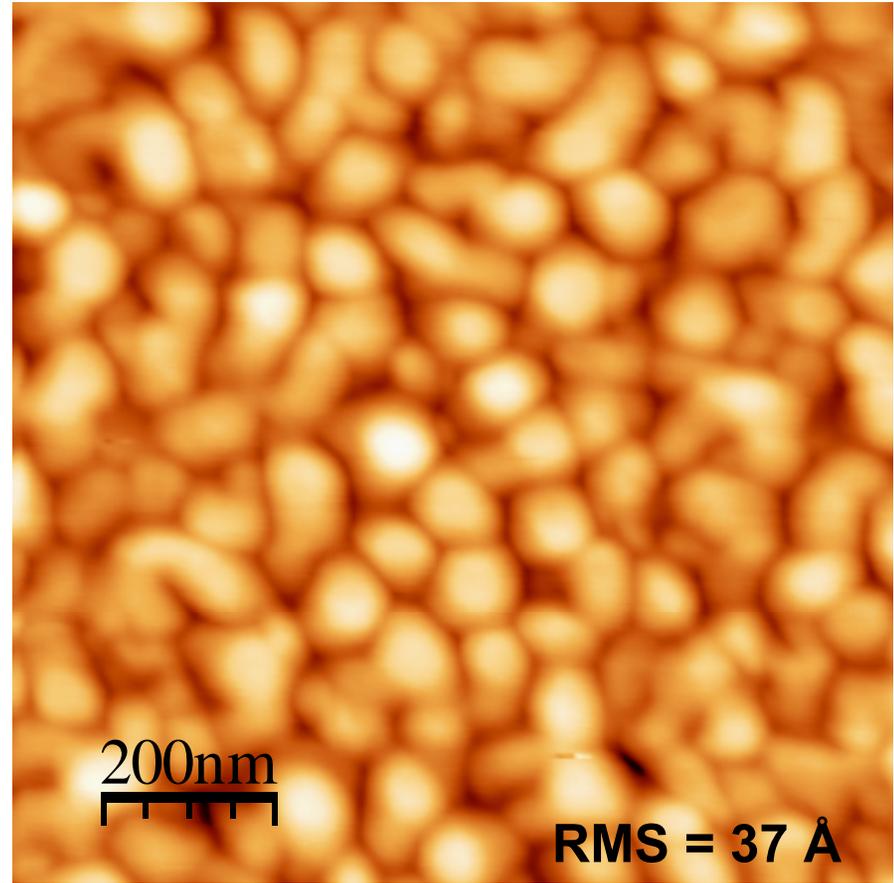




STM – Scanning Tunneling Microscopy



Au/mica - *TSG*

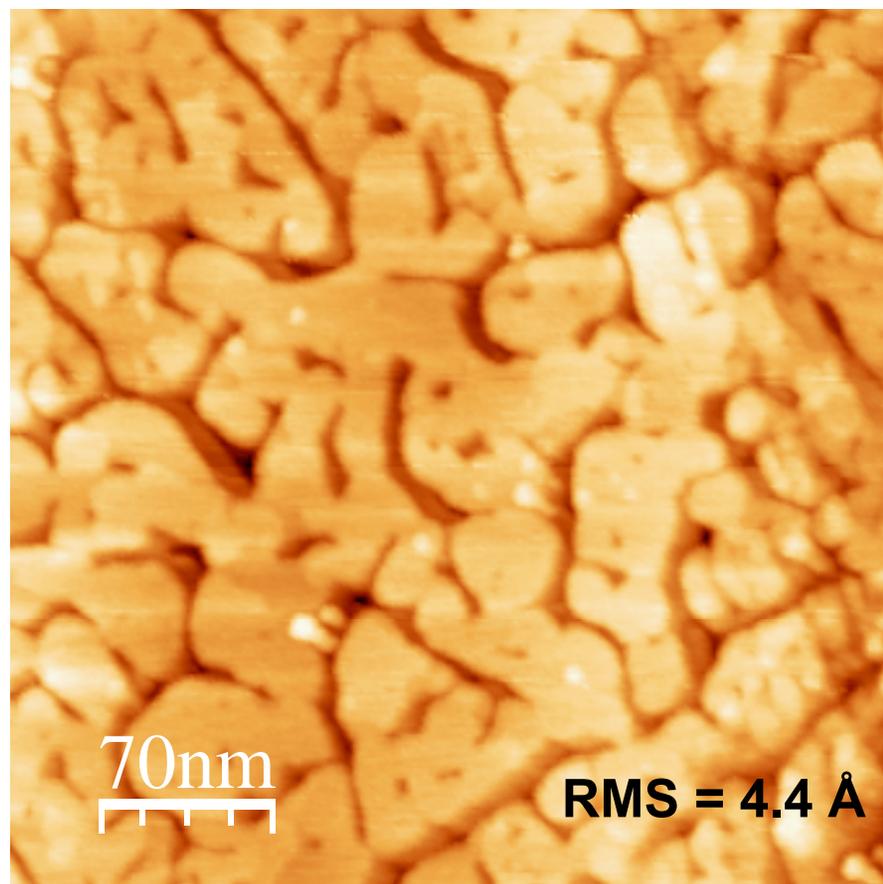
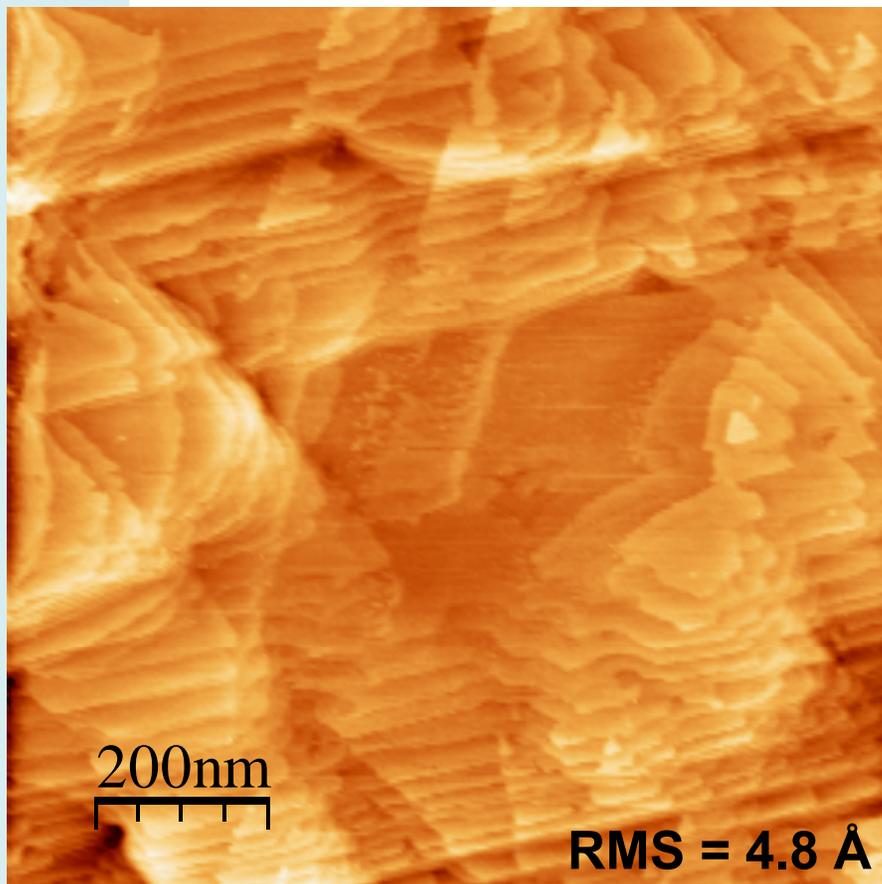
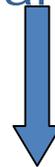
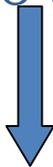


Au/Si

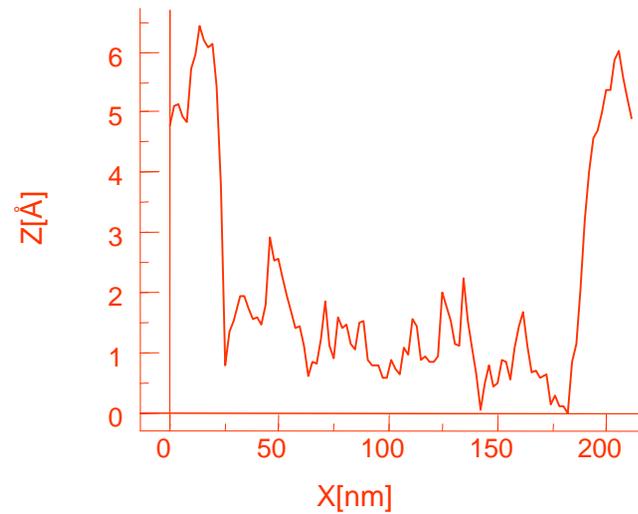
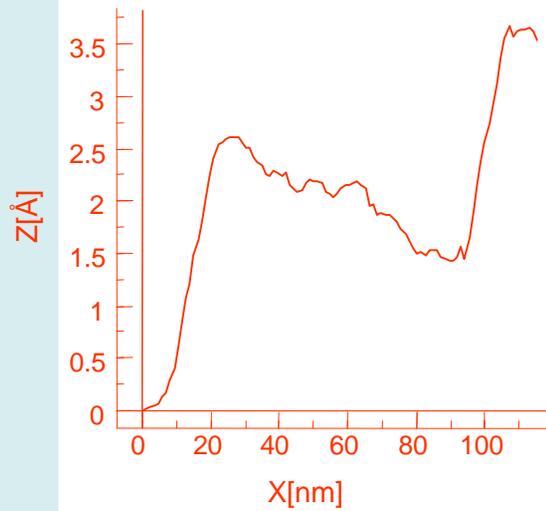
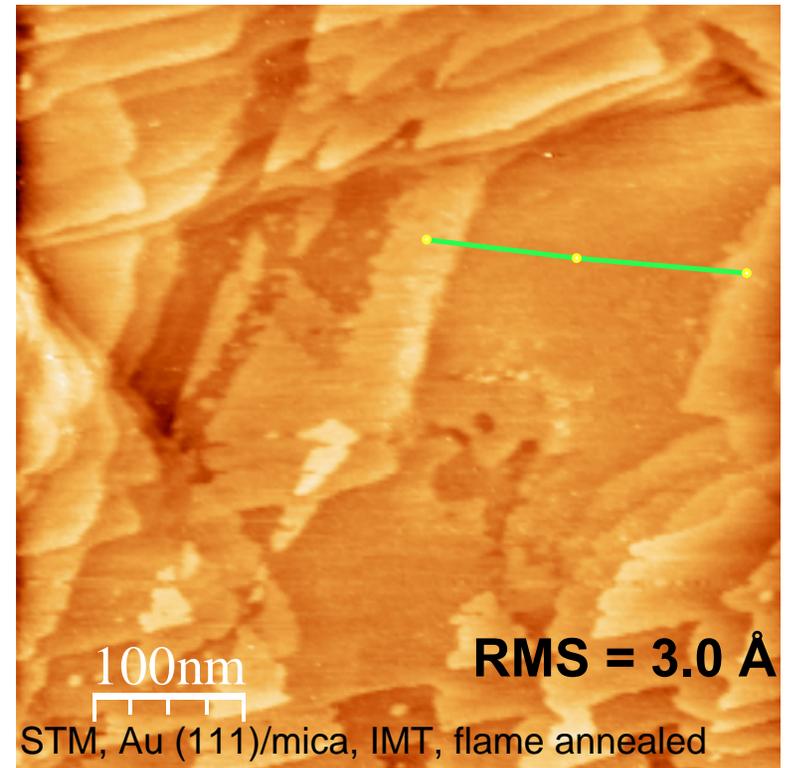
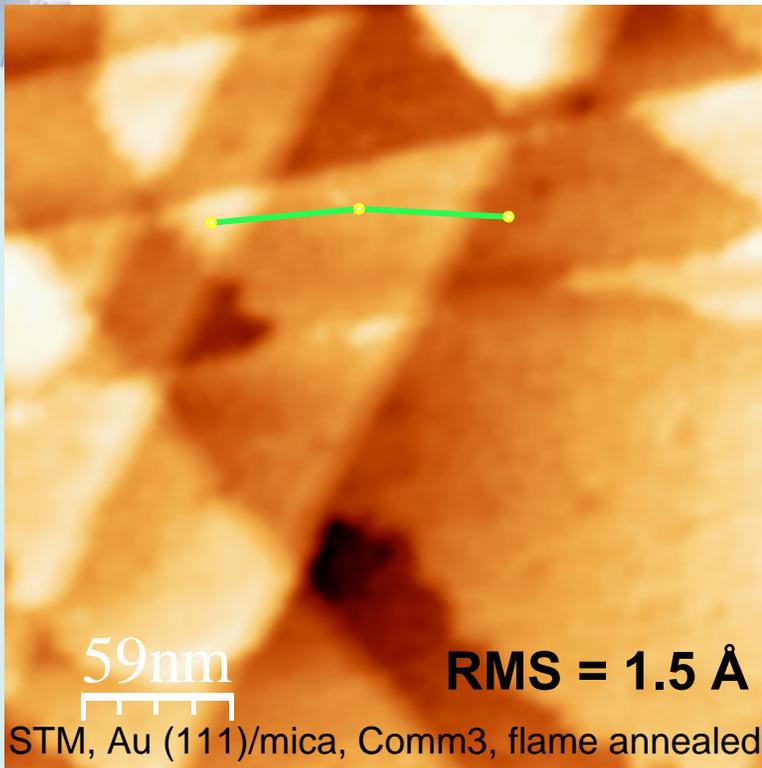


STM, Au (111)/mica

Flame annealed vs. non-flame annealed

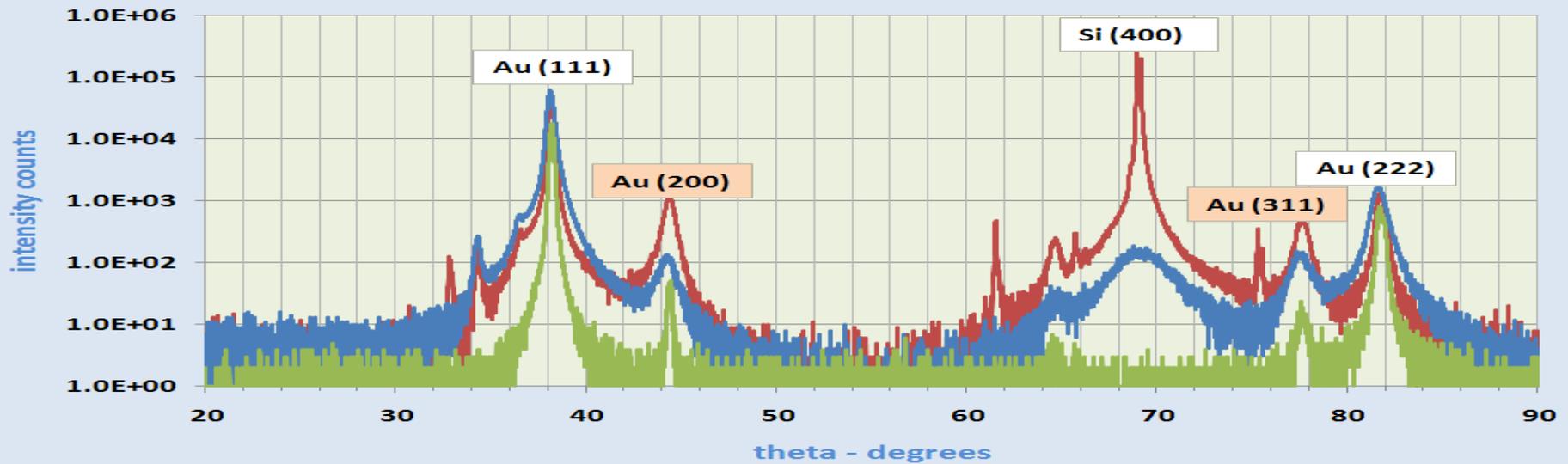


STM, Au (111)/mica - flame annealed

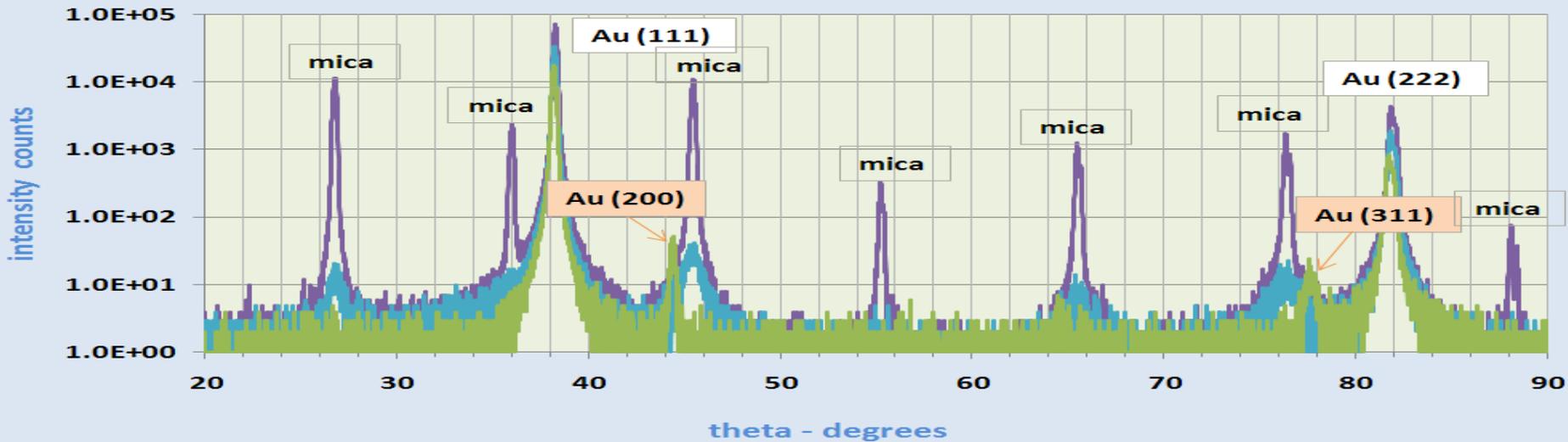




XRD characterisation



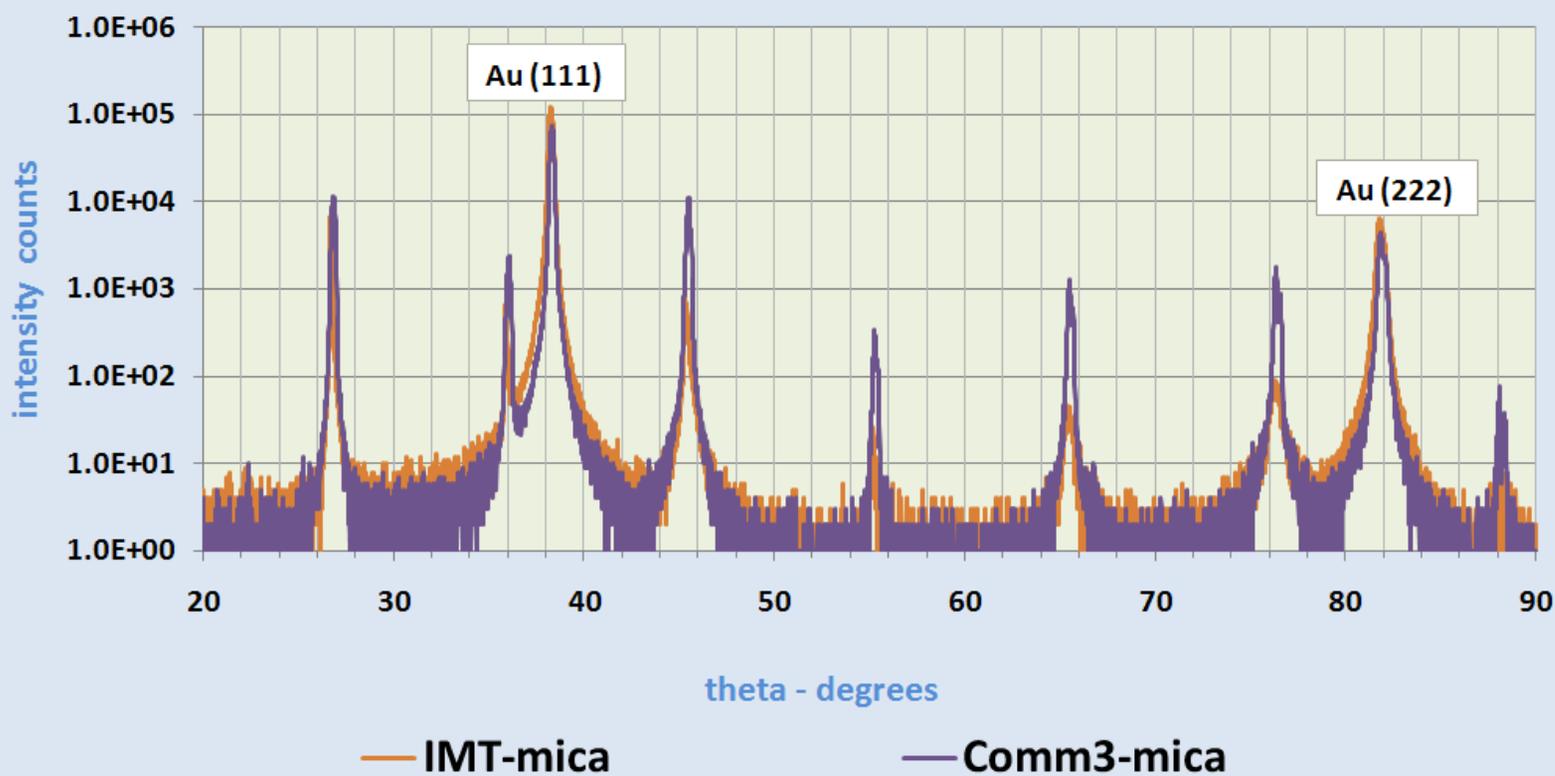
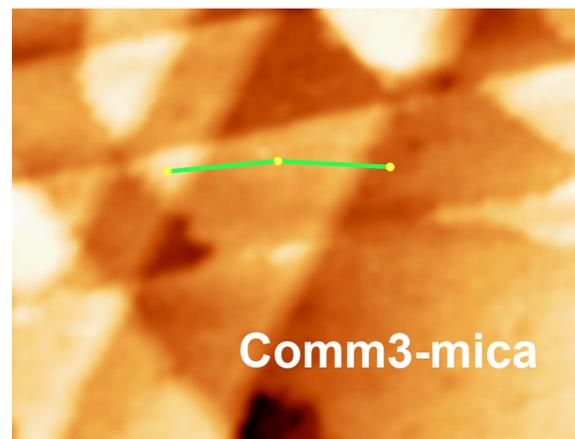
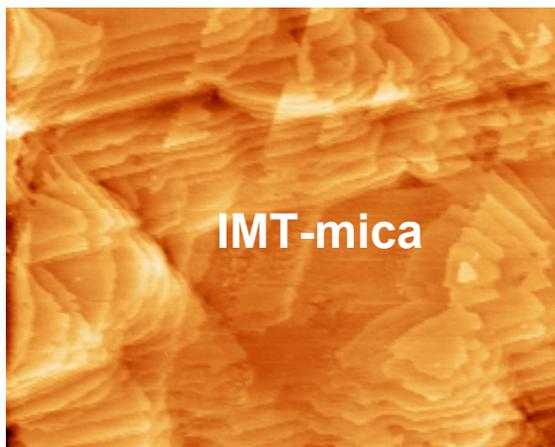
— IMT-Cr/Si — Comm1-Cr/Si — Comm2-Cr/boro.glass



— Comm3-mica — Comm1-mica — Comm2-Cr/boro.glass

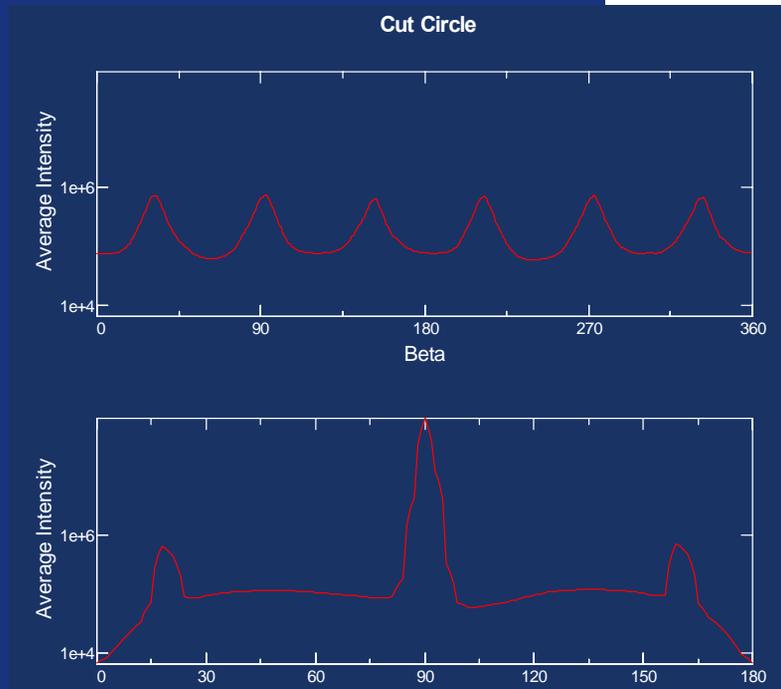
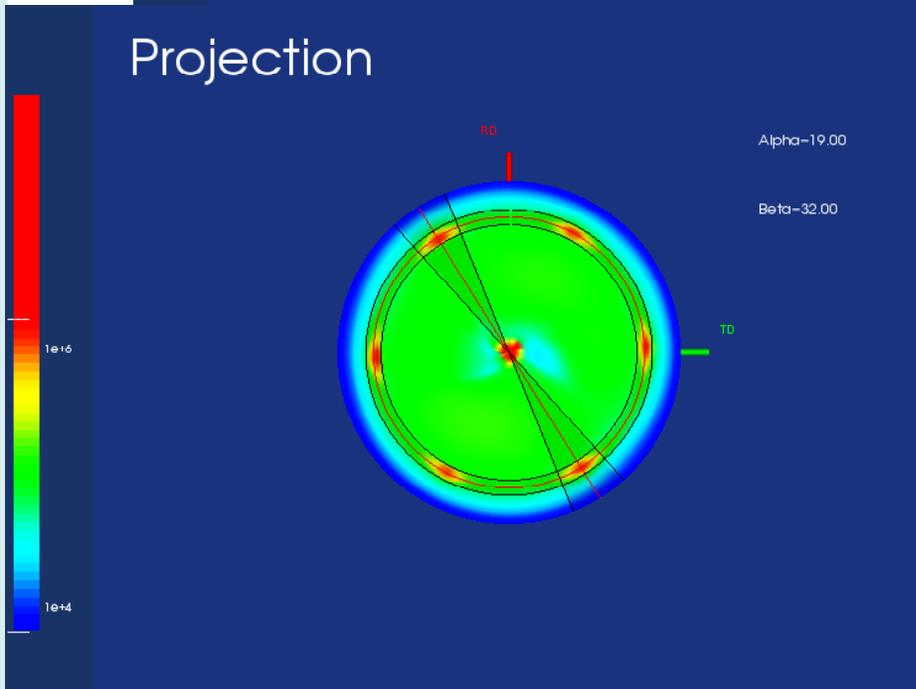
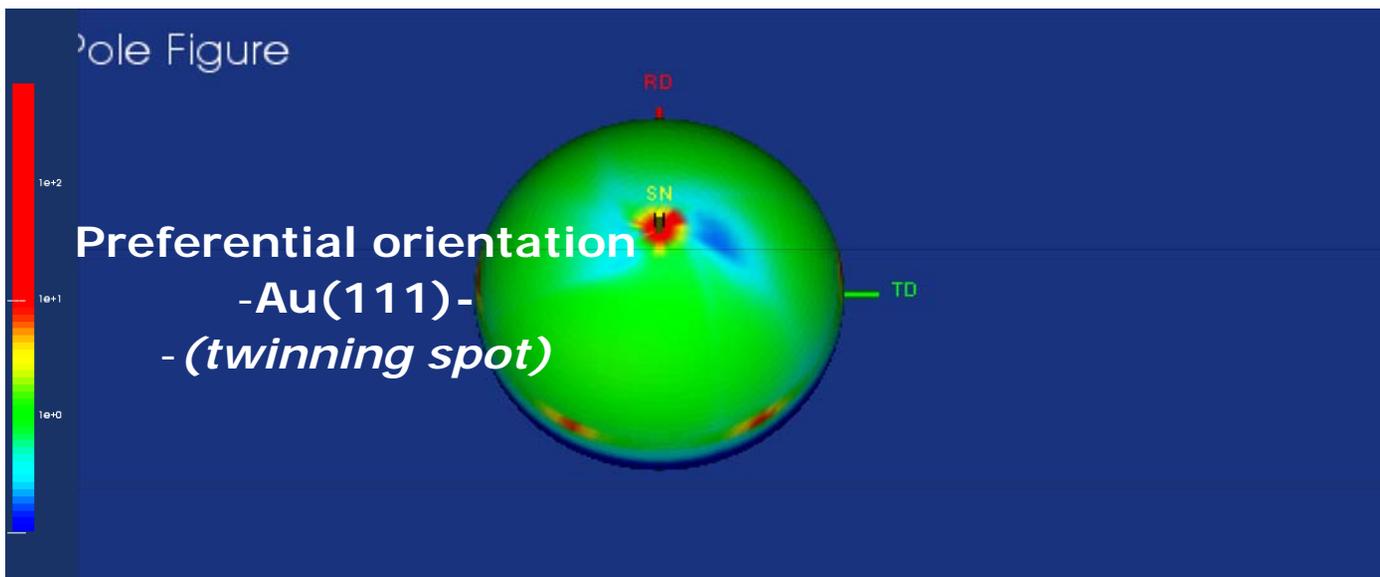


XRD characterisation

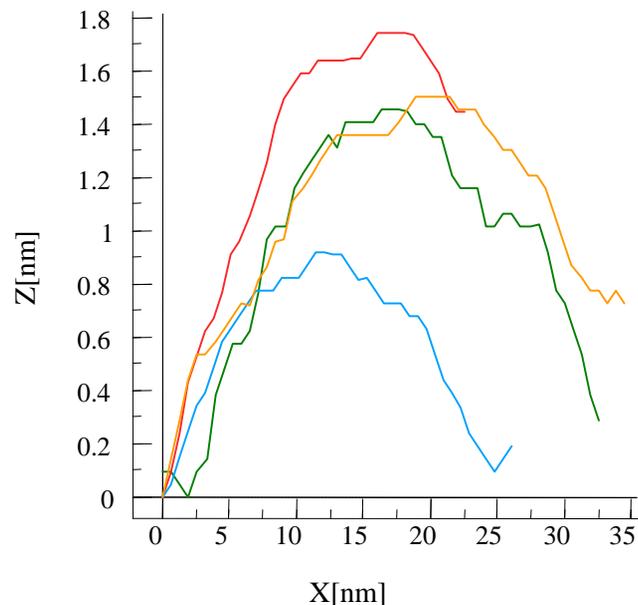
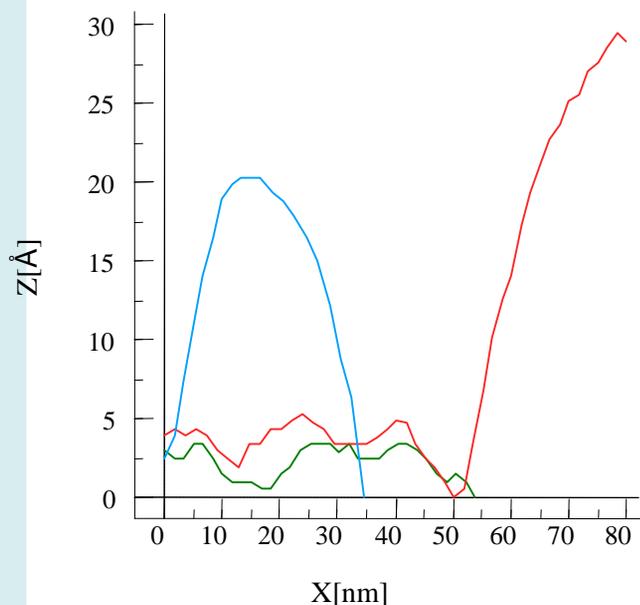
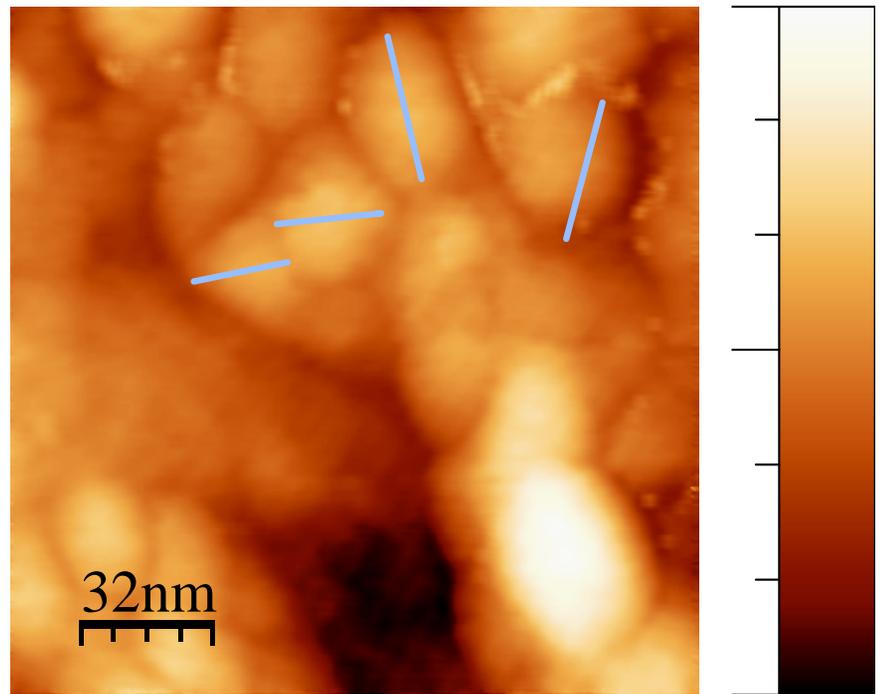
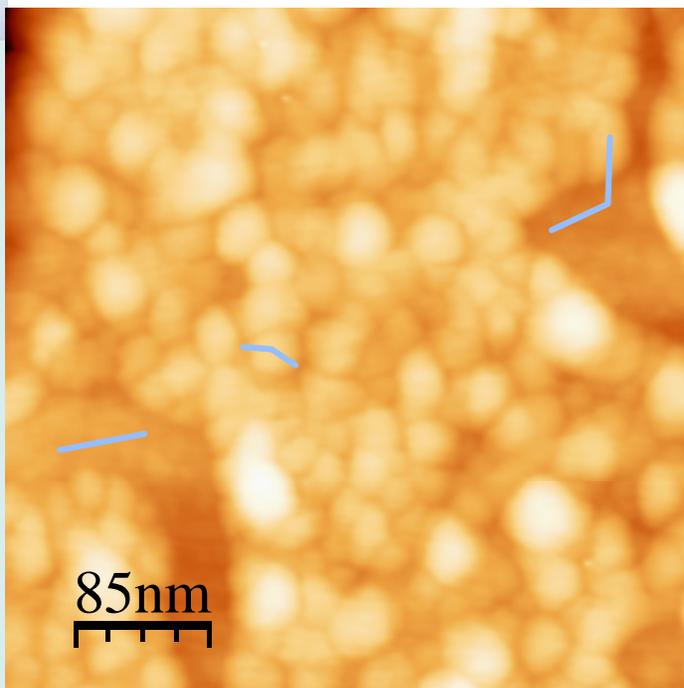




XRD characterisation



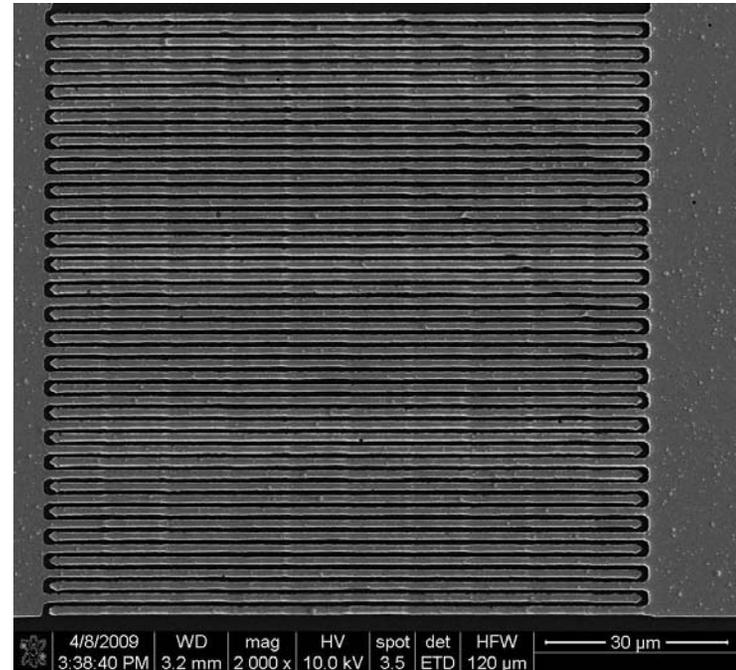
Human Serum Albumine/Au (111)



•Graphene – metallic nanoparticles decorated

•Graphene decorated with:

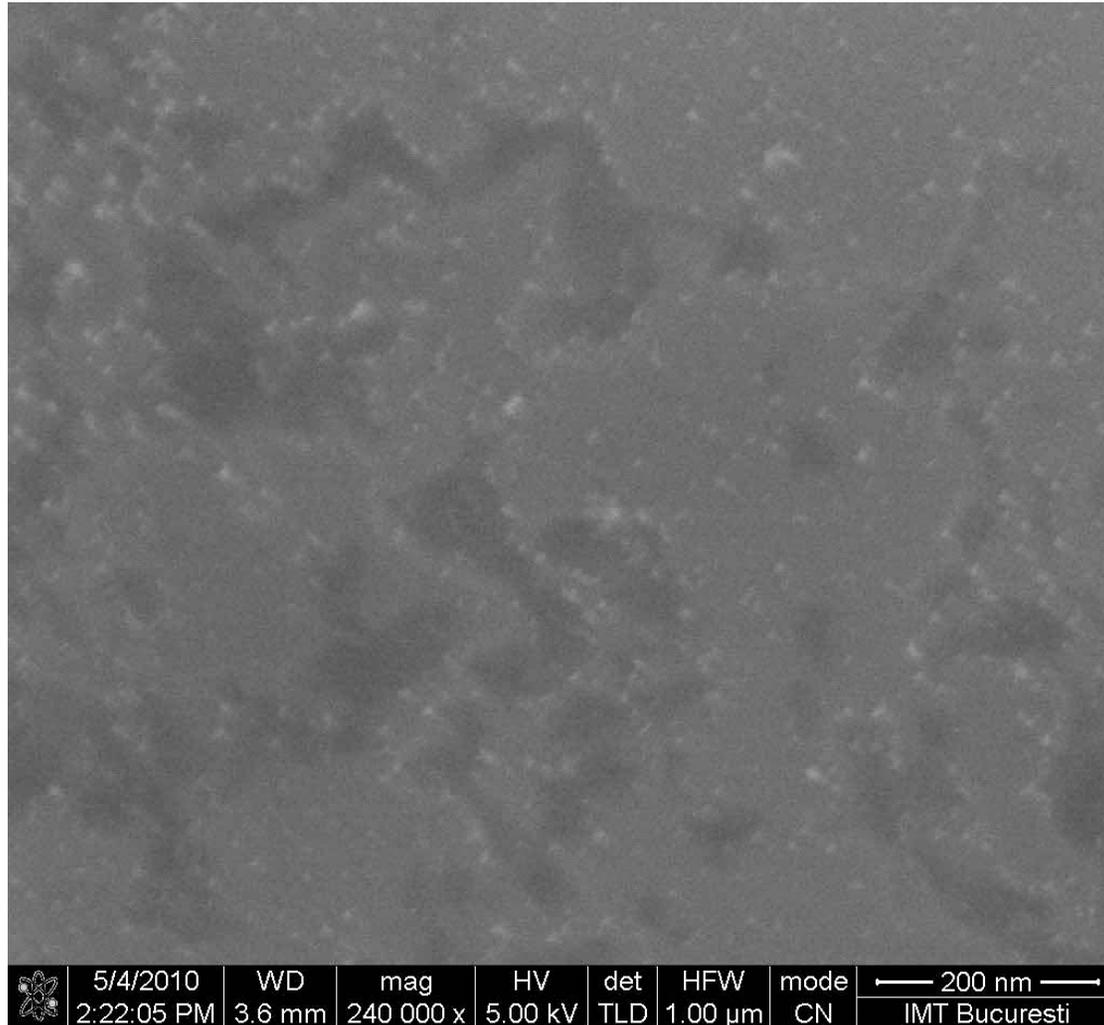
- Au nanoparticles
- Ag nanoparticles



SEM - IDT



- Graphene – Au nanoparticles decorated



Graphene decorated with nanoAu

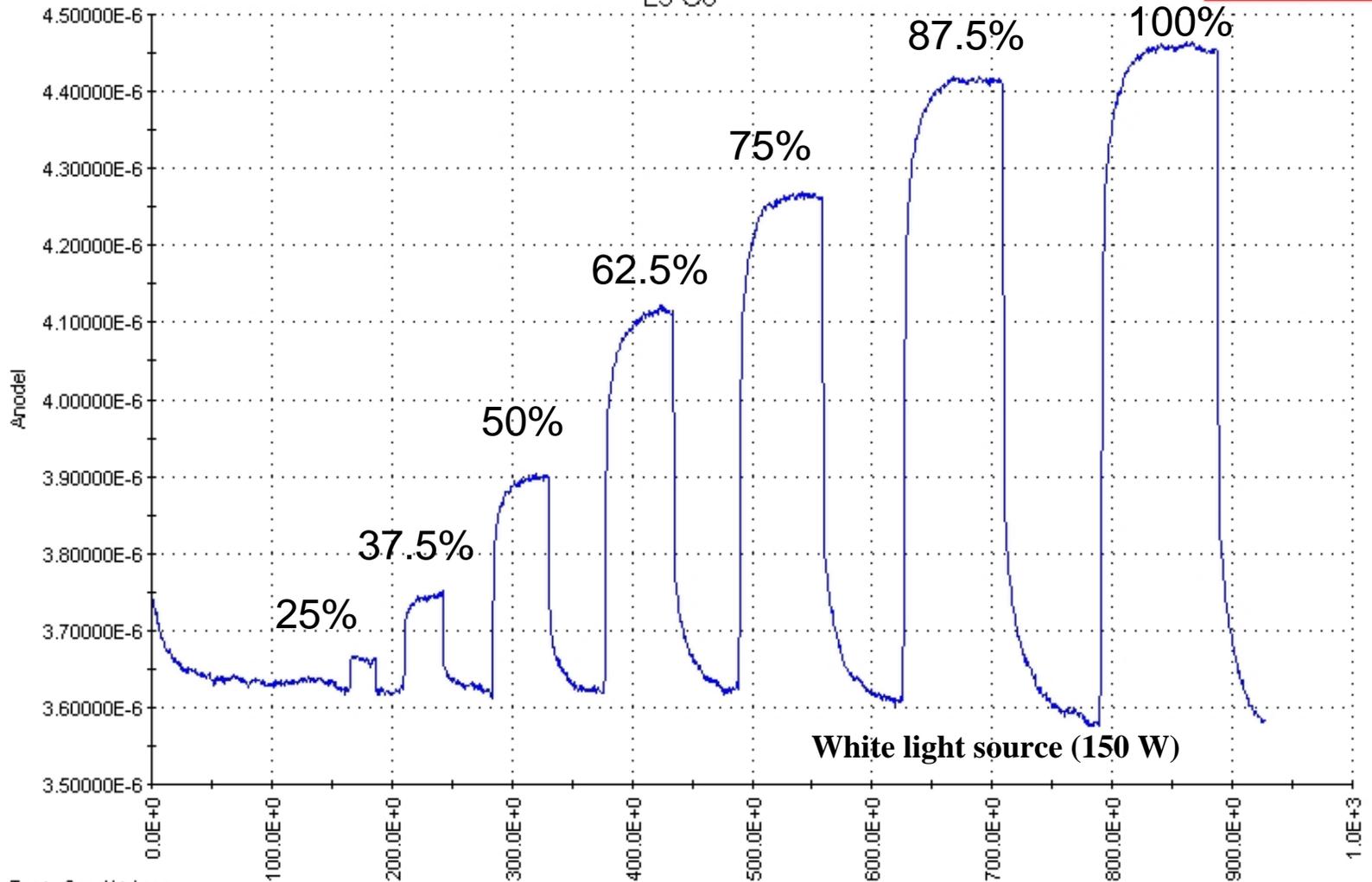


Photocurrent Graphene – nanoAu

06/08/2010 15:20:13

L9 C8

KEITHLEY



Test Conditions
Anode: V.Bias
Bias: 0.1
Cathode: V.Bias
Bias: 0

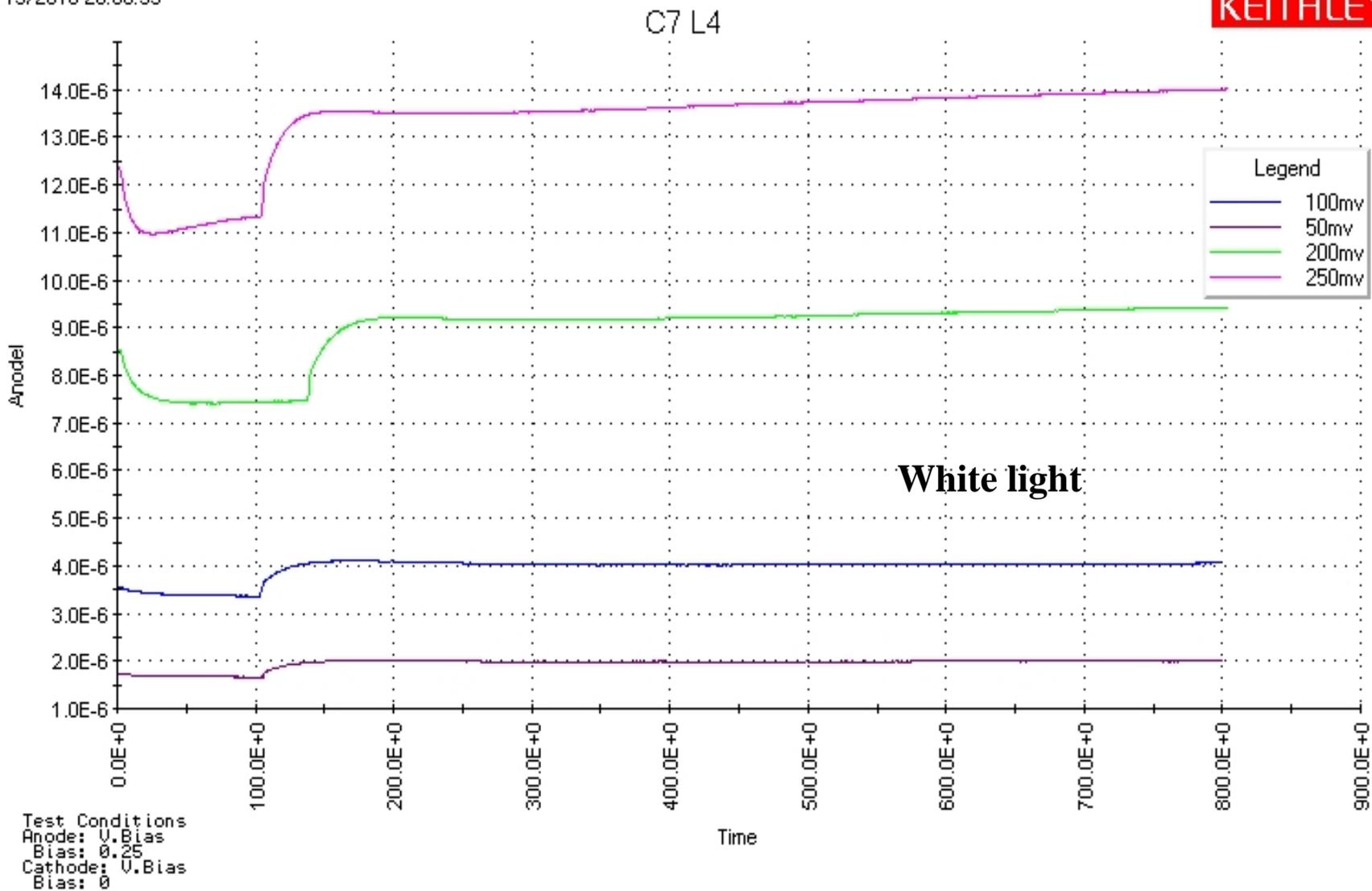
Time



Photocurrent Graphene – nanoAg

07/19/2010 20:00:39

KEITHLEY



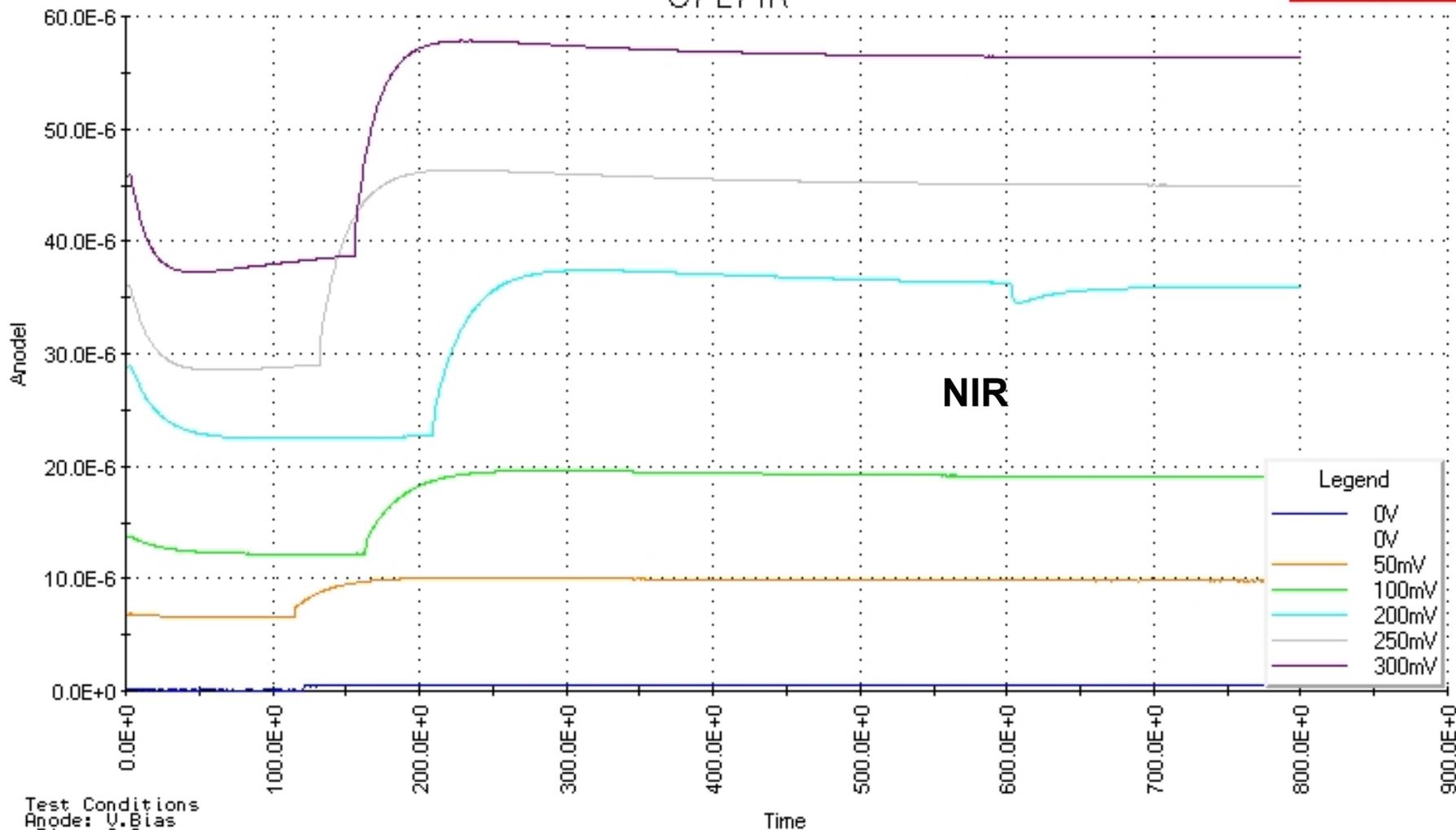


Photocurrent Graphene – nanoAg

07/20/2010 04:05:18

KEITHLEY

C7 L7 IR



Test Conditions
Anode: U.Bias
Bias: 0.3
Cathode: U.Bias
Bias: 0

Time

